

NPN Silicon Transistor FJP5555

Features

- Fast Speed Switching
- Wide Safe Operating Area
- High Voltage Capability
- This Device is Pb-Free and Halide Free

Applications

- Electronic Ballast
- Switch Mode Power Supplies

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

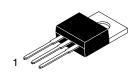
| Symbol | Parameter | Value | Unit |
|-------------------|--------------------------------------|-------------|------|
| BV _{CBO} | Collector-Base Voltage | 1050 | V |
| BV _{CEO} | Collector-Emitter Voltage | 400 | V |
| BV _{EBO} | Emitter-Base Voltage | 14 | V |
| I _C | Collector Current (DC) | 5 | Α |
| I _{CP} | Collector Current (Pulse) | 10 | Α |
| Ι _Β | Base Current (DC) | 2 | Α |
| I _{BP} | I _{BP} Base Current (Pulse) | | Α |
| T_J | T _J Junction Temperature | | °C |
| T _{STG} | Storage Temperature | -55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

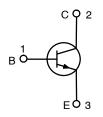
THERMAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

| Symbol | Parameter | | Value | Unit |
|-----------------|--|------------------------|-------|------|
| P_{D} | Total Device Dissipation | T _A = 25 °C | 1.38 | W |
| | | T _C = 25 °C | 75 | W |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient (Note 1) | | 90 | °C/W |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case (Note 2) | | 1.66 | °C/W |

- 1. $R_{\theta JA}$ test board and fixture under natural convection, JESD51-10 recommended thermal test board.
- 2. $R_{\theta JC}$ test fixture under infinite cooling condition.



TO-220-3LD CASE 340AT



- 1. Base
- 2. Collector
- 3. Emitter

MARKING DIAGRAM

AWWYZ J5555

A = Assembly Location
WW = Work Week

Y = Year

Z = Lot Traceability

J5555 = Specific Device Code

ORDERING INFORMATION

| Device | Package | Shipping | | |
|-----------|------------|-------------------|--|--|
| FJP5555TU | TO-220-3LD | 1000 Units / Tube | | |

FJP5555

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted) (Note 3)

| Symbol | Parameter | Test Condition | Min | Тур | Max | Unit |
|----------------------|--------------------------------------|---|------|-----|-----|------|
| BV _{CBO} | Collector-Base Voltage | I _C = 500 μA, I _E = 0 | 1050 | - | - | V |
| BV _{CEO} | Collector-Emitter Voltage | I _C = 5 mA, I _B = 0 | 400 | - | - | V |
| BV _{EBO} | Emitter-Base Voltage | I _E = 500 μA, I _C = 0 | 14 | - | - | V |
| h _{FE} | DC Current Gain | V _{CE} = 5 V, I _C = 10 mA | 10 | - | - | |
| | | V _{CE} = 3 V, I _C = 0.8 A | 20 | - | 40 | |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 1 A, I _B = 0.2 A | - | - | 0.5 | V |
| | | I _C = 3.5 A, I _B = 1.0 A | - | - | 1.5 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = 3.5 A, I _B = 1.0 A | - | - | 1.2 | V |
| C _{ob} | Output Capacitance | V _{CB} = 10 V, f = 1 MHz | - | 45 | - | pF |
| t _{ON} | Turn-On Time | V _{CC} = 125 V, I _C = 0.5 A, | - | - | 1.0 | μs |
| tsтg | Storage Time | I_{B1} = 45 mA, I_{B2} = 0.5 A, R_L = 250 Ω | _ | - | 1.2 | μs |
| t _F | Fall Time | 1 | _ | - | 0.3 | μs |
| t _{ON} | Turn-On Time | $V_{CC} = 250 \text{ V}, I_C = 2.5 \text{ A}, \\ I_{B1} = 0.5 \text{ A}, I_{B2} = 1.0 \text{ A}, \\ R_L = 100 \Omega$ | - | - | 2.0 | μs |
| tsтG | Storage Time | | - | _ | 2.5 | μs |
| t _F | Fall Time | 1 | - | - | 0.3 | μs |
| EAS | Avalanche Energy | L = 2 mH | 6 | - | - | mJ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse test: pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$

FJP5555

TYPICAL PERFORMANCE CHARACTERISTICS

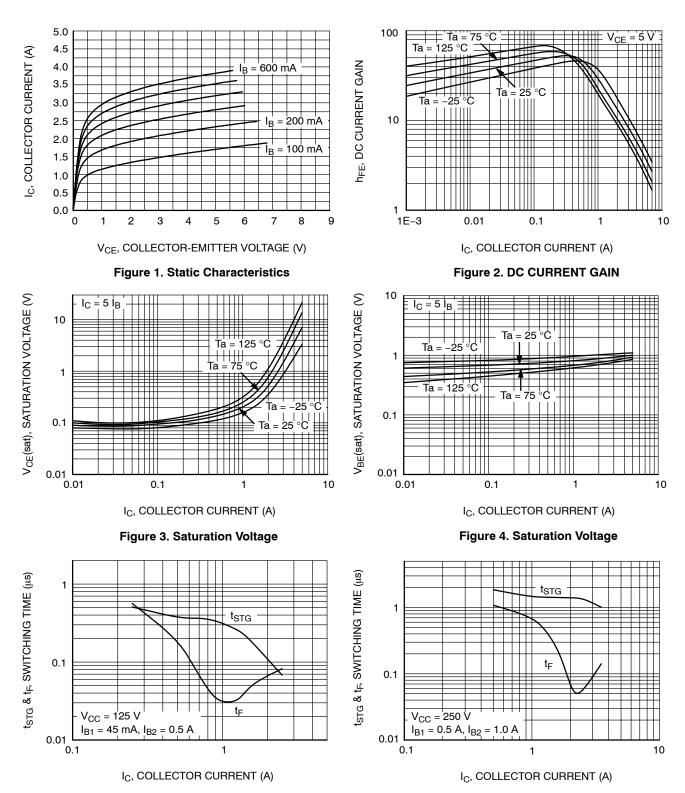


Figure 5. Resistive Load Switching Figure 6. Resistive Load Switching

FJP5555

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

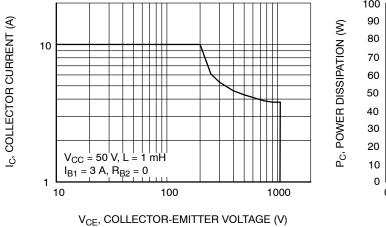
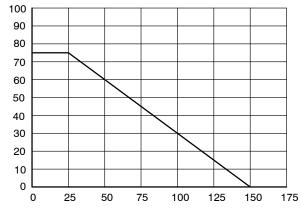
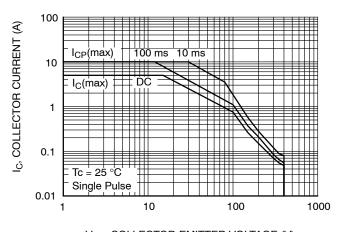


Figure 7. Reverse Biased Safe Operating Area



 $\mathsf{T}_\mathsf{C},\,\mathsf{CASE}\,\mathsf{TEMPERATURE}$ (°C) Figure 8. Power Derating





V_{CE}, COLLECTOR-EMITTER VOLTAGE (V)

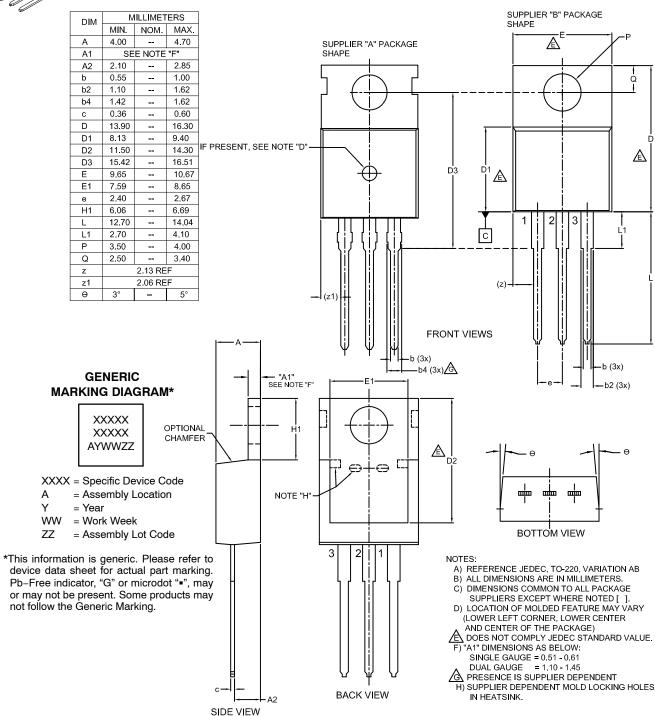
Figure 9. Forward Biased Safe Operating Area



DIM MIN. A 4.00 A1 SE A2 2.10 b 0.55

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DATE 08 AUG 2022



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